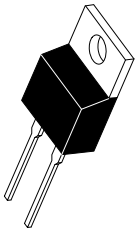
Switch-mode Power Rectifiers

MBR1080G, MBR1090G, MBR10100G, NRVB10100G

SCHOTTKY BARRIER RECTIFIERS 10 AMPERES, 80 to 100 VOLTS



TO−220AC
CASE 221B

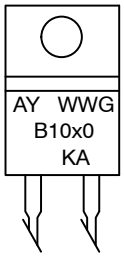
Features

- Guard−Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V−0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- AEC−Q101 Qualified and PPAP Capable
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb−Free*

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating:
  - ♦ Human Body Model = 3B
  - ♦ Machine Model = C

MARKING DIAGRAM



A	= Assembly Location
Y	= Year
WW	= Work Week
G	= Pb−Free Package
B10x0	= Device Code
x	= 8, 9 or 10
KA	= Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
MBR10100G	TO−220 (Pb−Free)	50 Units/Rail

DISCONTINUED (Note 1)

MBR1080G	TO−220 (Pb−Free)	50 Units/Rail
MBR1090G	TO−220 (Pb−Free)	50 Units/Rail
NRVB10100G	TO−220 (Pb−Free)	50 Units/Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on www.onsemi.com.

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MAXIMUM RATINGS

Rating	Symbol	MBR/NRVB			Unit
		1080	1090	10100	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	80	90	100	V
Average Rectified Forward Current (Rated V_R) T_C = 133°C	$I_{F(AV)}$	10			A
Peak Repetitive Forward Current (Rated V_R, Square Wave, 20 kHz) T_C = 133°C	I_{FRM}	20			A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	150			A
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I_{RRM}	0.5			A
Operating Junction Temperature (Note 1)	T_J	−65 to +175			°C
Storage Temperature	T_{stg}	−65 to +175			°C
Voltage Rate of Change (Rated V_R)	dv/dt	10,000			V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction−to−Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	2.0	°C/W
Maximum Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	60	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) (i_F = 10 Amps, T_C = 125°C) (i_F = 10 Amps, T_C = 25°C) (i_F = 20 Amps, T_C = 125°C) (i_F = 20 Amps, T_C = 25°C)	v_F	 0.7 0.8 0.85 0.95	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, T_C = 125°C) (Rated dc Voltage, T_C = 25°C)	i_R	 6.0 0.10	mA

2. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

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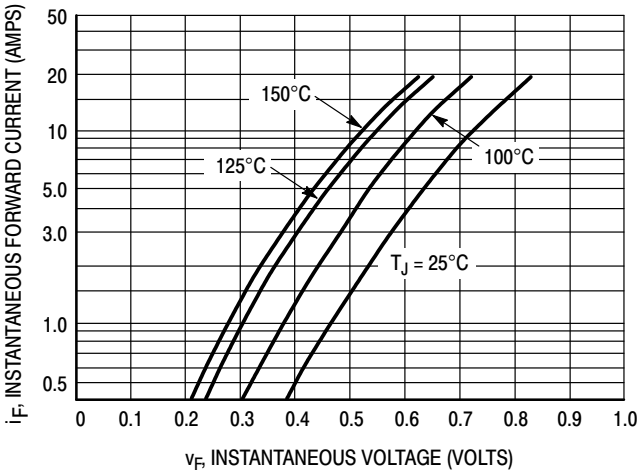

Figure 1. Typical Forward Voltage

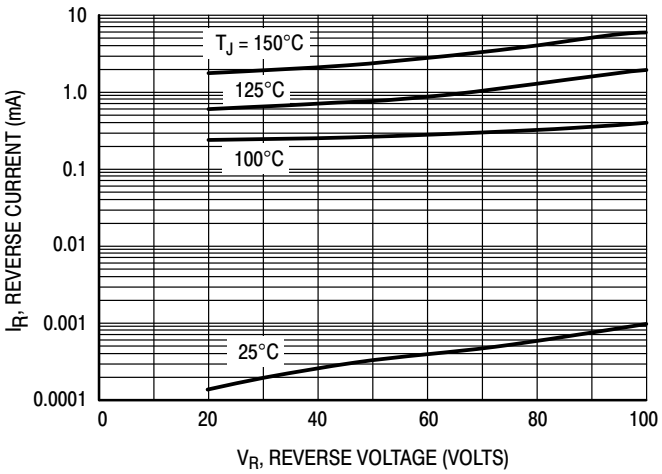

Figure 2. Typical Reverse Current

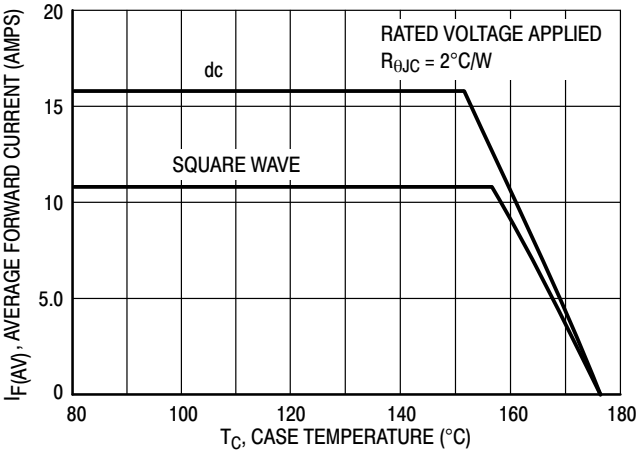

Figure 3. Typical Current Derating, Case

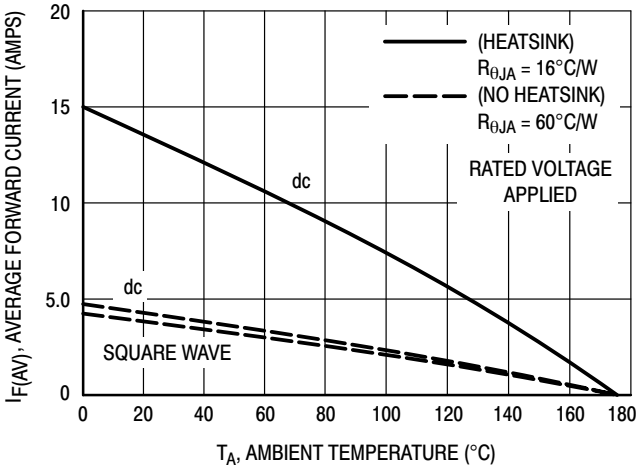

Figure 4. Typical Current Derating, Ambient

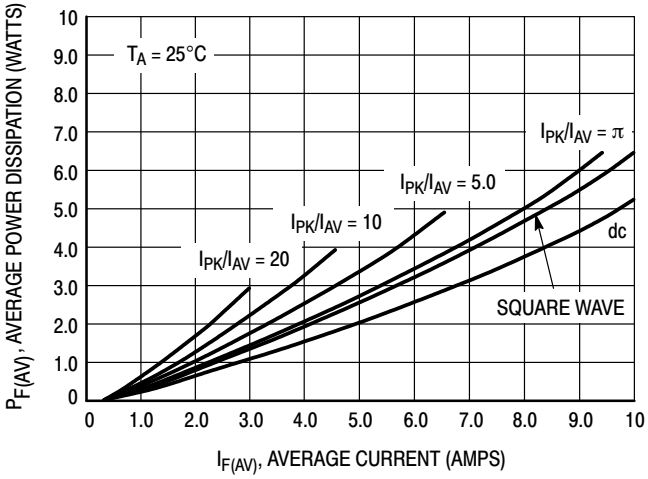

Figure 5. Forward Power Dissipation

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REVISION HISTORY

Revision	Description of Changes	Date
2	MBR1080G, MBR1090G, NRVB10100G OPN Marked as Discontinued + Rebranded the Data Sheet to onsemi format	6/23/2025

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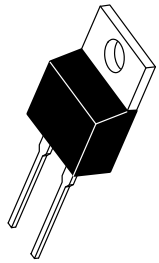
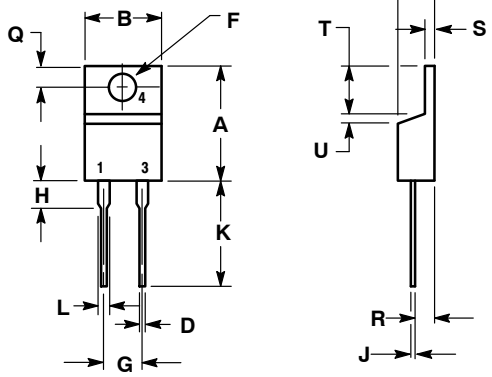
TO−220, 2−LEAD
CASE 221B−04
ISSUE F

DATE 12 APR 2013



SCALE 1:1



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.595	0.620	15.11	15.75
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.82
D	0.025	0.039	0.64	1.00
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
H	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

STYLE 1:
PIN 1. CATHODE
2. N/A
3. ANODE
4. CATHODE

STYLE 2:
PIN 1. ANODE
2. N/A
3. CATHODE
4. ANODE

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